

Low frequency amplifier (30V, 1.5A)

US6X6

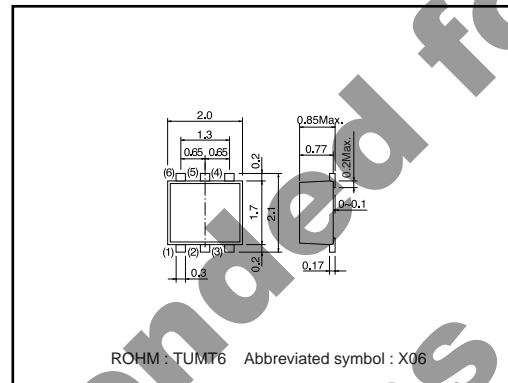
●Application

Low frequency amplifier
Driver

●Features

- 1) A collector current is large.
- 2) $V_{CE(sat)}$: max. 350mV
At $I_c = 1A / I_B = 50mA$

●Dimensions (Unit : mm)



●Absolute maximum ratings (Ta=25°C)

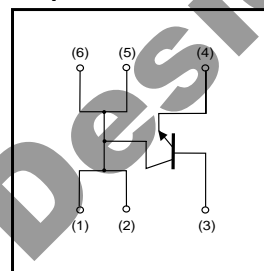
Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	30	V
Collector-emitter voltage	V_{CEO}	30	V
Emitter-base voltage	V_{EBO}	6	V
Collector current	I_c	1.5	A
	I_{CP}	3	A *1
Power dissipation	P_c	400	mW *2
		1.0	W *3
Junction temperature	T_j	150	°C
Range of storage temperature	T_{stg}	-55 to +150	°C

*1 Single pulse, $P_w=1ms$

*2 Each Terminal Mounted on a Recommended

*3 Mounted on a 25mm×25mm×1.0.8mm ceramic substrate

●Equivalent circuit



●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	30	—	—	V	$I_c=10\mu A$
Collector-emitter breakdown voltage	BV_{CEO}	30	—	—	V	$I_c=1mA$
Emitter-base breakdown voltage	BV_{EBO}	6	—	—	V	$I_E=10\mu A$
Collector cutoff current	I_{CBO}	—	—	100	nA	$V_{CB}=30V$
Emitter cutoff current	I_{EBO}	—	—	100	nA	$V_{EB}=6V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	140	350	mV	$I_c=1A, I_B=50mA$
DC current gain	h_{FE}	270	—	680	—	$V_{CE}=2V, I_c=100mA^*$
Transition frequency	f_T	—	300	—	MHz	$V_{CE}=2V, I_E=-100mA, f=100MHz^*$
Collector output capacitance	C_{ob}	—	11	—	pF	$V_{CB}=10V, I_E=0A, f=1MHz$

* Pulsed

Transistors

●Packaging specifications

Type	Package	Taping
	Code	TR
	Basic ordering unit (pieces)	3000
US6X6		○

●Electrical characteristic curves

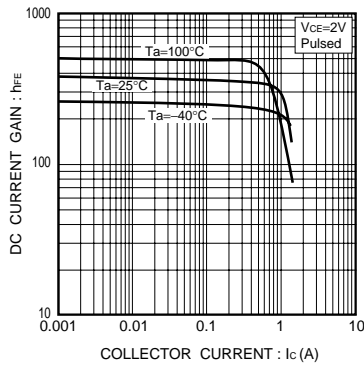


Fig.1 DC current gain vs. collector current

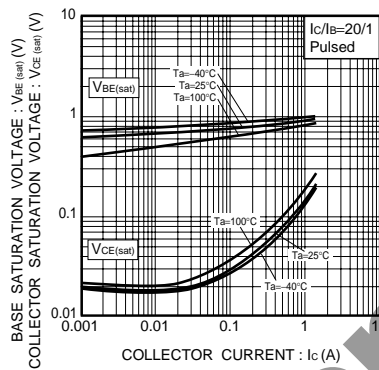


Fig.2 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current

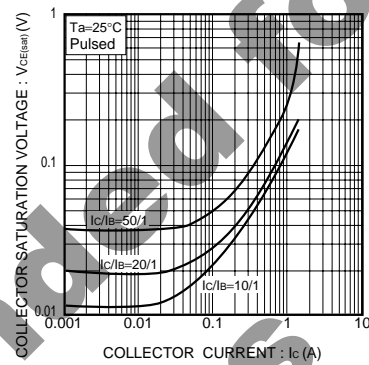


Fig.3 Collector-emitter saturation voltage vs. collector current

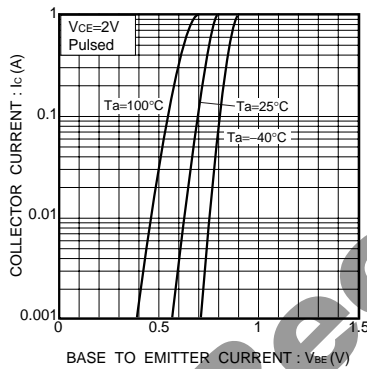


Fig.4 Grounded emitter propagation characteristics

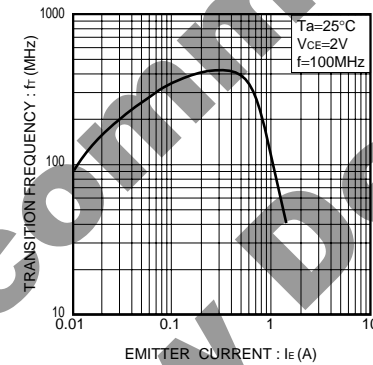


Fig.5 Gain bandwidth product vs. emitter current

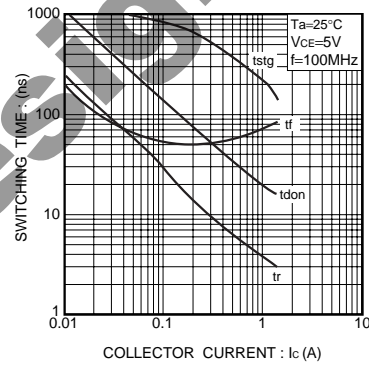


Fig.6 Switching time

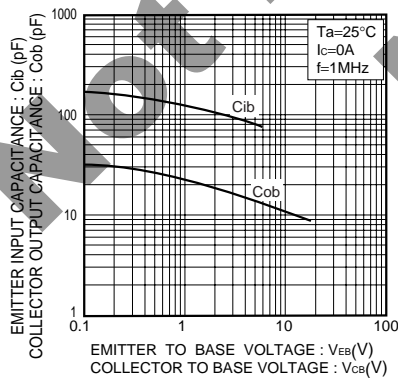


Fig.7 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

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